Preferred Device

# **Amplifier Transistors**

### **NPN Silicon**

### **Features**

• Pb-Free Packages are Available\*

### **MAXIMUM RATINGS**

| Rating   | Symbol                            | Value       | Unit        |
|--|-----------------------------------|-------------|-------------|
| Collector – Emitter Voltage<br>2N5550<br>2N5551                    | V <sub>CEO</sub>                  | 140<br>160  | Vdc         |
| Collector – Base Voltage<br>2N5550<br>2N5551                       | V <sub>CBO</sub>                  | 160<br>180  | Vdc         |
| Emitter – Base Voltage   | V <sub>EBO</sub>                  | 6.0         | Vdc         |
| Collector Current – Continuous                                     | I <sub>C</sub>                    | 600         | mAdc        |
| Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C | P <sub>D</sub>                    | 625<br>5.0  | mW<br>mW/°C |
| Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C | P <sub>D</sub>                    | 1.5<br>12   | W<br>mW/°C  |
| Operating and Storage Junction<br>Temperature Range                | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

### THERMAL CHARACTERISTICS

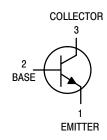
| Characteristic                          | Symbol          | Max  | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 200  | °C/W |
| Thermal Resistance, Junction-to-Case    | $R_{	heta JC}$  | 83.3 | °C/W |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



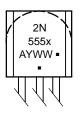
### ON Semiconductor®

### http://onsemi.com





### **MARKING DIAGRAM**



x = 0 or 1

A = Assembly Location

Y = Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic   |                                      | Symbol                | Min                  | Max                    | Unit         |
|--|--------------------------------------|-----------------------|----------------------|------------------------|--------------|
| OFF CHARACTERISTICS  |                                      |                       | <u> </u>             | 1                      |              |
| Collector-Emitter Breakdown Voltage (Note 1) (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)   | 2N5550<br>2N5551                     | V <sub>(BR)</sub> CEO | 140<br>160           | -<br>-                 | Vdc          |
| Collector – Base Breakdown Voltage ( $I_C = 100 \mu Adc, I_E = 0$ )  | 2N5550<br>2N5551                     | V <sub>(BR)CBO</sub>  | 160<br>180           | -<br>-                 | Vdc          |
| Emitter–Base Breakdown Voltage $(I_E=10~\mu Adc,~I_C=0)$   |                                      | V <sub>(BR)EBO</sub>  | 6.0                  | _                      | Vdc          |
|  | 2N5550<br>2N5551<br>2N5550<br>2N5551 | Ісво                  | -<br>-<br>-<br>-     | 100<br>50<br>100<br>50 | nAdc<br>μAdc |
| Emitter Cutoff Current (V <sub>EB</sub> = 4.0 Vdc, I <sub>C</sub> = 0)   |                                      | I <sub>EBO</sub>      | _                    | 50                     | nAdc         |
| ON CHARACTERISTICS (Note 1)  | <del></del>                          |                       |                      |                        |              |
| DC Current Gain ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ ) ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )                 | 2N5550<br>2N5551<br>2N5550<br>2N5551 | h <sub>FE</sub>       | 60<br>80<br>60<br>80 | -<br>-<br>250<br>250   | -            |
| $(I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$  | 2N5550<br>2N5551                     |                       | 20<br>30             | -<br>-                 |              |
| Collector – Emitter Saturation Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 5.0 mAdc) | Both Types<br>2N5550<br>2N5551       | V <sub>CE(sat)</sub>  | -<br>-<br>-          | 0.15<br>0.25<br>0.20   | Vdc          |
| Base – Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mAdc}$ )    | Both Types<br>2N5550<br>2N5551       | V <sub>BE(sat)</sub>  | -<br>-<br>-          | 1.0<br>1.2<br>1.0      | Vdc          |
| SMALL-SIGNAL CHARACTERISTICS   |                                      |                       |                      |                        |              |
| Current-Gain — Bandwidth Product<br>(I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)  |                                      | f <sub>T</sub>        | 100                  | 300                    | MHz          |
| Output Capacitance<br>(V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)  |                                      | C <sub>obo</sub>      | _                    | 6.0                    | pF           |
| Input Capacitance<br>(V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)  | 2N5550<br>2N5551                     | C <sub>ibo</sub>      | -<br>-               | 30<br>20               | pF           |
| Small–Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)   |                                      | h <sub>fe</sub>       | 50                   | 200                    | -            |
| Noise Figure (I <sub>C</sub> = 250 $\mu$ Adc, V <sub>CE</sub> = 5.0 Vdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)                            | 2N5550<br>2N5551                     | NF                    | -<br>-               | 10<br>8.0              | dB           |

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

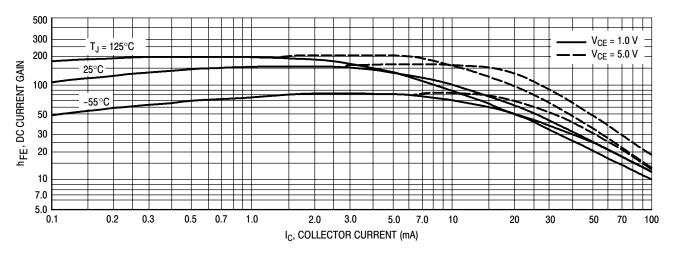


Figure 1. DC Current Gain

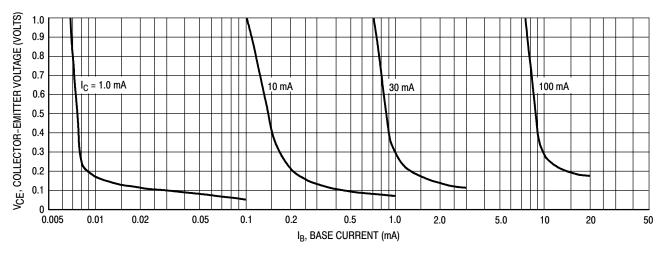


Figure 2. Collector Saturation Region

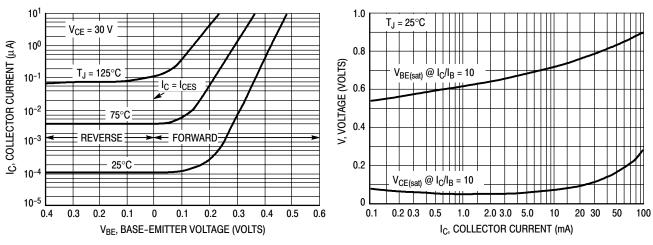
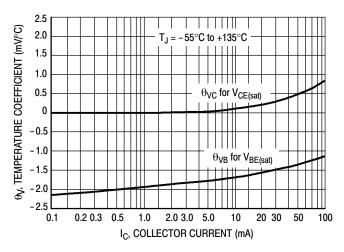


Figure 3. Collector Cut-Off Region

Figure 4. "On" Voltages



**Figure 5. Temperature Coefficients** 

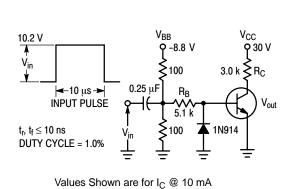


Figure 6. Switching Time Test Circuit

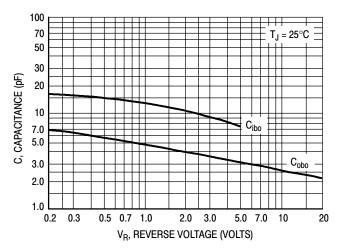


Figure 7. Capacitances

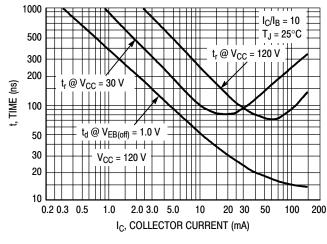


Figure 8. Turn-On Time

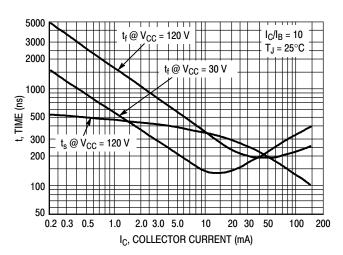


Figure 9. Turn-Off Time

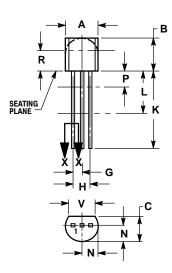
### **ORDERING INFORMATION**

| Device      | Package            | Shipping <sup>†</sup>  |  |
|-------------|--------------------|------------------------|--|
| 2N5550      | TO-92              |                        |  |
| 2N5550G     | TO-92<br>(Pb-Free) | 5000 Units / Box       |  |
| 2N5550RLRA  | TO-92              |                        |  |
| 2N5550RLRAG | TO-92<br>(Pb-Free) | 2000 / Tape & Reel     |  |
| 2N5550RLRP  | TO-92              |                        |  |
| 2N5550RLRPG | TO-92<br>(Pb-Free) | 2000 / Tape & Ammo Box |  |
| 2N5551      | TO-92              |                        |  |
| 2N5551G     | TO-92<br>(Pb-Free) | 5000 Units / Box       |  |
| 2N5551RL1   | TO-92              |                        |  |
| 2N5551RL1G  | TO-92<br>(Pb-Free) | 2000 (7                |  |
| 2N5551RLRA  | TO-92              | 2000 / Tape & Reel     |  |
| 2N5551RLRAG | TO-92<br>(Pb-Free) |                        |  |
| 2N5551RLRM  | TO-92              |                        |  |
| 2N5551RLRMG | TO-92<br>(Pb-Free) |                        |  |
| 2N5551RLRP  | TO-92              |                        |  |
| 2N5551RLRPG | TO-92<br>(Pb-Free) | 2000 / Tape & Ammo Box |  |
| 2N55551ZL1  | TO-92              |                        |  |
| 2N55551ZL1G | TO-92<br>(Pb-Free) |                        |  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

TO-92 **TO-226AA** CASE 29-11 **ISSUE AL** 





#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- 744.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R
  IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| С   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.021 | 0.407  | 0.533  |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| J   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| P   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| V   | 0.135  |       | 3.43   |        |

STYLE 1:

PIN 1. EMITTER

2 BASE

3. COLLECTOR

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